

M611x Series

5 x 7 mm, 3.0, 3.3 & 5.0 Volt, HCMOS or Clipped Sinewave,
Precision TCXO/TCVTCXO

Product Features

- Tight stability (0.3 ppm) over wide industrial temperature range (-40 °C to +85 °C)
- 3.0 V, 3.3 V and 5.0 V versions
- Wide frequency range 8-52 MHz
- Low phase noise
- Excellent G-Sensitivity performance: 1.5 ppb/G
- Tri-state Function



Product Description

MtronPTI's M611x Series TCXO's and TCVTCXO's provide design engineers with low voltage, surface mount products with extremely tight stability (to ± 0.3 ppm) over temperature and time. Specially processed crystals enable the M611x to achieve consistent long-term stability and minimal frequency shift after reflow. Our processing also enables us to achieve excellent g-sensitivity (1.5 ppb/g). The low phase noise (-155 dBc/Hz at 100 kHz) makes the M611x ideal for those design engineers working on all types of systems as the reference timing source.

Product Applications

The M611x Series is ideally suited for a wide range of applications such as GPS, military, avionics, test and measurement, WLAN, WiMax base stations (see Fig 2.), point to point/multi-point radios, medical equipment, frequency synthesis, frequency translation and land mobile radio. Standard output for the M611x series is HCMOS compatible or clipped sinewave and draws as little as 1.5 mA with a 3.3 volt supply at 13 MHz. This low power consumption provides an advantage over similarly specified ovenized oscillators for power-sensitive applications. The M611x series offers ± 9.2 ppm minimum pull range with excellent tuning linearity performance for critical PLL applications. This series is available in frequencies from 8 to 52 MHz, and is offered in a ceramic surface mount platform with industry standard 5 x 7 mm footprint.

Product Ordering Information

Ordering Information		M611x	1	J	T	C	N	00.0000 MHz
Product Series								
M6110: 5.0 V								
M6111: 3.3 V								
M6112: 3.0 V								
Temperature Range								
1: 0°C to +70°C								
2: -40°C to +85°C								
6: -20°C to +70°C								
Stability								
P: ± 0.3 ppm								
G: ± 0.5 ppm								
J: ± 1.0 ppm								
K: ± 2.0 ppm								
H: ± 2.5 ppm								
Output Type								
T: Voltage Controlled With Tristate (VCTCXO)								
F: No Voltage Control With Tristate (TCXO)								
Output Waveform								
C: 45/55% HCMOS								
S: Clipped Sine Wave								
Package/Lead Configurations								
N: Leadless Ceramic								
Frequency (customer specified)								

M6110Sxxx, M6111Sxxx & M6112Sxxx - Contact factory for datasheets.

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Performance Characteristics

	Electrical Specifications					
	Parameter	Symbol	Min.	Typ.	Max.	Units
	Frequency Range	F _O	8		52	MHz
	Operating Temperature	T _A	-40		+85	°C
	Storage Temperature	T _{STG}	-55		+125	°C
	Frequency Tolerance @ +25°C		-1.0		+1.0	ppm
	Frequency Stability					
	Stability Vs. Reflow		-1.0		+1.0	ppm
	Frequency Vs. Supply			±0.2		ppm
	Frequency Vs. Load			±0.2		ppm
	Aging (First Year)		-1.0		+1.0	ppm
	Aging (First Year)		-2.0		+2.0	ppm
	Aging (10 Year)		-3.0		+3.0	ppm
	Aging (10 Year)		-5.0		+5.0	ppm
	Supply Voltage (V _S)		-5.0		+5.0	%
	Supply Current (I _D)			2.2	3.3	mA
				3.5	5.0	mA
				6.0	9.2	mA
				1.5	2.2	mA
				1.8	2.7	mA
				3.0	4.5	mA
	Output Logic Levels	V _{OL} V _{OH}	80		20	%V _S %V _S
	Waveform Symmetry		45		55	%
	Rise/Fall Time				8	ns
	Output Load			15 10/10		pF Kohm/pF
	Frequency Adjustment		±9.2			ppm
	Control Voltage Range		0.3 0.5		3.0 4.5	Volts Volts
	Input Leakage Current		-50		+50	µA
	Input Resistance		100			Kohm
	Linearity				3	%
	Modulation Bandwidth		2 kHz			
	Tristate Function (Pad 8)		70			%V _S
					30	%V _S
	Tristate Leakage Current		-100		+100	µA
	Phase Noise			-95		dBc/Hz
	(Typical 10 MHz CMOS)			-125		dBc/Hz
				-145		dBc/Hz
				-152		dBc/Hz
				-155		dBc/Hz
Environmental	Shock	MIL-STD-202, Method 213, Condition C				100 g
	Vibration	MIL-STD-202, Methods 201 & 204				10 g from 10 to 2000 Hz
	Solderability	EIAJ-STD-002				
	Package	5.0 x 7.0 x 2.0 mm, 10-pad SMT				RoHS Compliant
	Max Soldering Conditions	See solder profile, Figure 1				

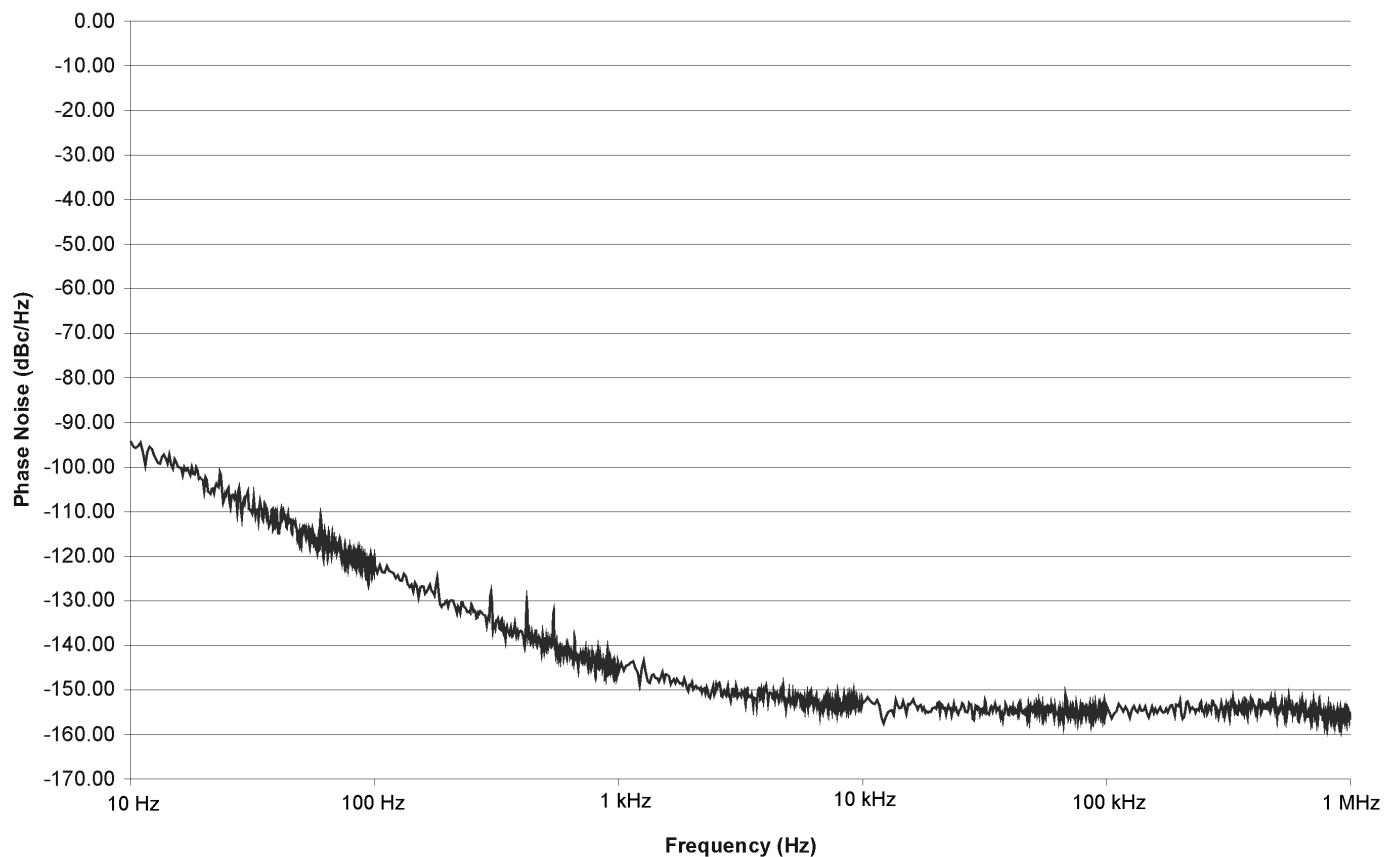
HCMOS Load – see load circuit diagram #2. Sinewave Load – see load circuit diagram #7.

M611x Series

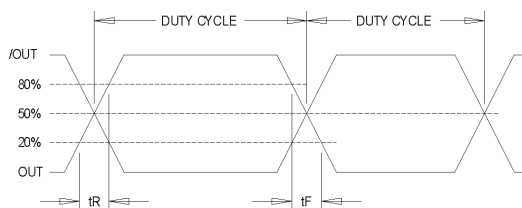
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Phase Noise Plot

M611x 10MHz Phase Noise



Output Waveform



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Handling Information

Although protection circuitry has been designed into the M611x oscillator, proper precautions should be taken to avoid exposure to electrostatic discharge (ESD) during handling and mounting. MtronPTI utilizes a human-body model (HBM) and a charged-device model (CDM) for ESD-susceptibility testing and protection design evaluation. ESD voltage thresholds are dependent on the circuit parameters used to define the mode. Although no industry-wide standard has been adopted for the CDM, a standard HBM (resistance = 1500 Ω , capacitance = 100 pF) is widely used and therefore can be used for comparison purposes. The HBM ESD threshold presented here was obtained using these circuit parameters.

Model	ESD Threshold, Minimum	Unit
Human Body	1500*	V
Charged Device	1500*	V

* MIL-STD-883D, Method 3015, Class 1



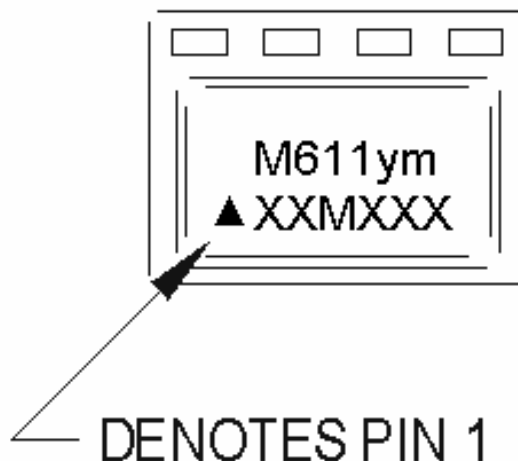
Quality Parameters

Environmental Specifications/Qualification Testing Performed on the M611x TCXO/TCVCXO		
Test	Test Method	Test Condition
Electrical Characteristics	Internal Specification	Per Specification
Frequency vs. Temperature	Internal Specification	Per Specification
Mechanical Shock	MIL-STD-202, Method 213, C	100 g, 6 ms
Vibration	MIL-STD-202, Method 201-204	10 g from 10-2000 Hz
Thermal Cycle	MIL-STD-883, Method 1010, B	-55 Deg. C to +125 Deg. C, 15 minute Dwell, 10 cycles
Aging	Internal Specification	168 Hours at 105 Degrees C
Gross Leak	MIL-STD-202, Method 112	30 Second Immersion
Fine Leak	MIL-STD-202, Method 112	Must meet 1×10^{-5}
Solderability	MIL-STD-883, Method 2003	8 Hour Steam Age – Must Exhibit 95% coverage
Resistance to Solvents	MIL-STD-883, Method 2015	Three 1 minute soaks
Terminal Pull	MIL-STD-883, Method 2004, A	2 Pounds
Lead Bend	MIL-STD-883, Method 2004, B1	1 Bending Cycle
Physical Dimensions	MIL-STD-883, Method 2016	Per Specification
Internal Visual	Internal Specification	Per Internal Specification

Part Marking Guide

Line 1: Indicates part family, year, month of production

Line 2: Indicates frequency

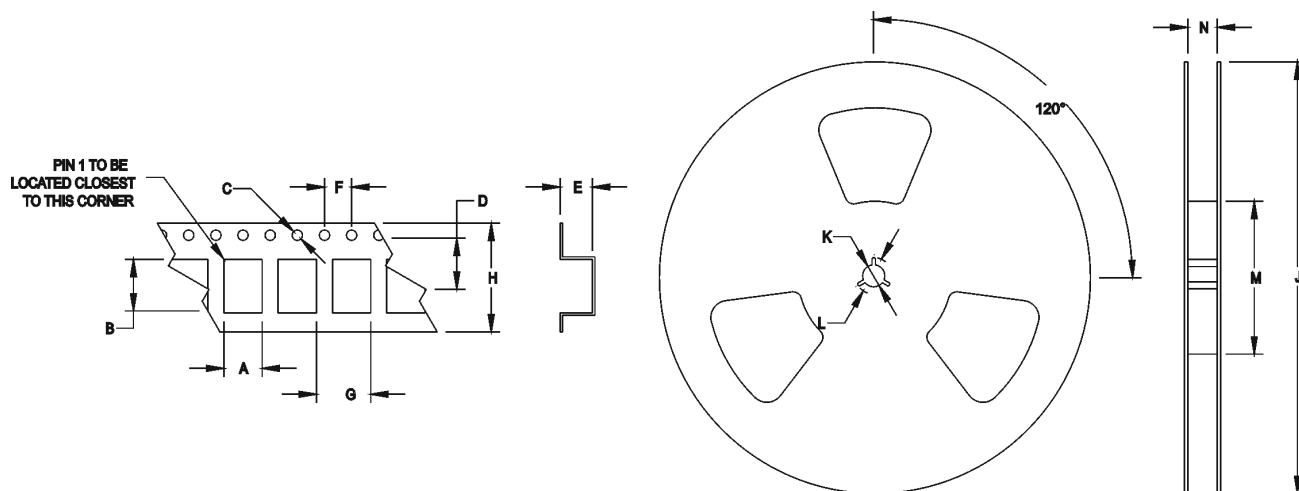


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Tape & Reel Specifications

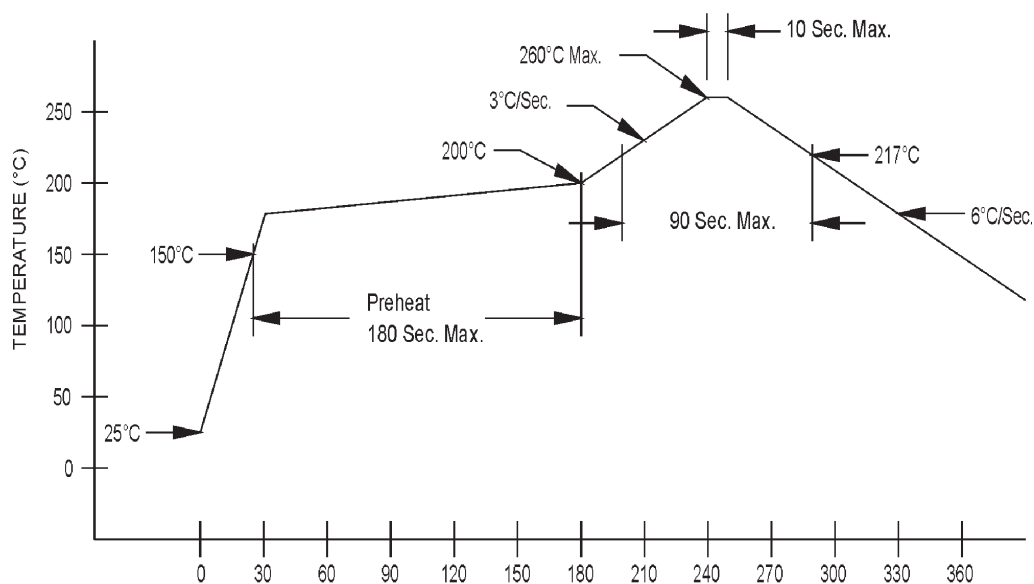
(all measurements are in mm)	A	B	C	D	E	F	G	H	J	K	L	M	N
M611x	5.40	7.40	1.55	7.50	2.60	2.00	4.00	16.00	330	13.00	20.20	100	16.40



Standard Tape and Reel: 1000 parts per reel

Maximum Soldering Conditions

+260°C REFLOW PROFILE (RoHS COMPLIANT SOLDER)



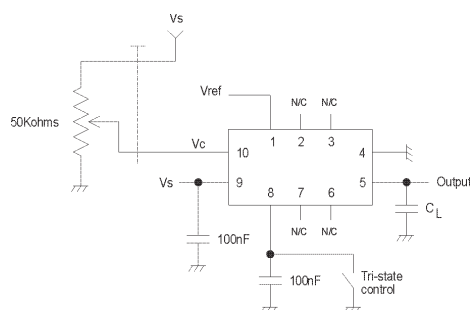
Solder Conditions

Note: Exceeding these limits may damage the device.

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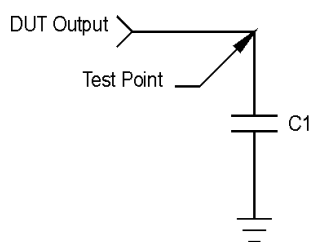
Typical Test Circuit



Load Circuit

Load Circuit #2 - HCMOS

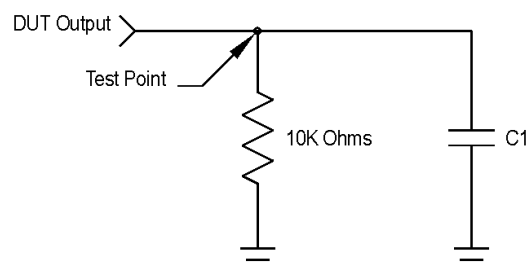
C1 = 15pF, 20pF, 30pF, 50pF, or Other as specified on the data sheet.



Note: Load capacitance includes probe and fixturing.

Load Circuit #7 - Clipped Sinewave TCXO/TCVTCXO

C1 = 10pF, 15pF, or Other as specified on the data sheet.



Note: Load capacitance includes probe and fixturing.

Product Revision Table

Date	Revision	PCN Number	Details of Revision

For custom products or additional specifications contact our sales team at
800.762.8800 (toll free) or 605.665.9321

For more information on this product visit the MtronPTI website at
www.mtronpti.com